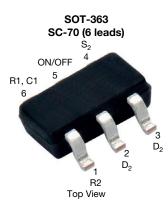
RoHS

COMPLIANT

HALOGEN FREE

Vishay Siliconix

Load Switch with Level-Shift

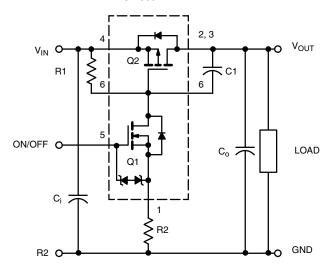


Marking Code: VD

| PRODUCT SUMMARY | | | | | | |
|---|-------------|--|--|--|--|--|
| V _{DS} (V) | 12 | | | | | |
| $R_{DS(on)}$ (Ω) at $V_{IN} = 4.5 \text{ V}$ | 0.200 | | | | | |
| $R_{DS(on)}$ (Ω) at $V_{IN} = 2.5 \text{ V}$ | 0.300 | | | | | |
| $R_{DS(on)}$ (Ω) at $V_{IN} = 1.8 \text{ V}$ | 0.508 | | | | | |
| I _D (A) | ± 1.1 | | | | | |
| Configuration | Level-shift | | | | | |

APPLICATION CIRCUITS

Si1865DDL



| COMPONENTS | | | | | | |
|------------|---|-------------------------------|--|--|--|--|
| R1 | Typical 10 k Ω to 1 M Ω a | | | | | |
| R2 | Optional slew-rate control | Typical 0 to 100 k Ω^a | | | | |
| C1 | Optional slew-rate control | Typical 1000 pF | | | | |

Note

Minimum R1 value should be at least 10 x R2 to ensure Q1 turn-on

FEATURES

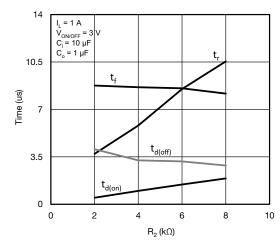
- Low R_{DS(on)} TrenchFET®
- 1.8 V to 12 V input
- 1.5 V to 8 V logic level control
- · Low profile, small footprint SC-70-6 package
- 2000 V ESD protection on input switch, V_{ON/OFF}
- Adjustable slew-rate
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · Load switch with level-shift
- Slew-rate control
- Portable / consumer devices

DESCRIPTION

The Si1865DDL includes a p- and n-channel MOSFET in a single SC-70-6 package. The low on-resistance p-channel TrenchFET is tailored for use as a load switch. The n-channel, with an external resistor, can be used as a level-shift to drive the p-channel load-switch. The n-channel MOSFET has internal ESD protection and can be driven by logic signals as low as 1.5 V. The Si1865DDL operates on supply lines from 1.8 V to 12 V, and can drive loads up to 1.1 A.

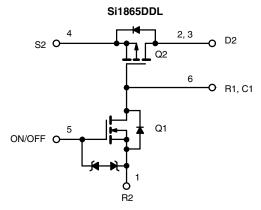


Switching Variation R2 at V_{IN} = 2.5 V, R1 = 20 k Ω

The Si1865DDL is ideally suited for high-side load switching in portable applications. The integrated n-channel level-shift device saves space by reducing external components. The slew rate is set externally so that rise-times can be tailored to different load types.



FUNCTIONAL BLOCK DIAGRAM



| ORDERING INFORMATION | | | | |
|---------------------------------|------------------|--|--|--|
| Package | SC-70 | | | |
| Lead (Pb)-free and halogen-free | Si1865DDL-T1-GE3 | | | |

| ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted) | | | | | |
|---|-----------------|-----------------------------------|------------|------|--|
| PARAMETER | | SYMBOL | LIMIT | UNIT | |
| Input voltage | | $V_{IN}(V_{DS2})$ | 12 | V | |
| On/off voltage | | V _{ON/OFF} | 8 | V | |
| Load aurrent | Continuous a, b | I. | ± 1.1 | | |
| Load current | Pulsed b, c | IL | ± 5 | Α | |
| Continuous intrinsic diode conduction ^a | | Is | -0.3 | | |
| Maximum power dissipation ^a | | P_{D} | 0.357 | W | |
| Operating junction and storage temperature range | | T _J , T _{stg} | -55 to 150 | °C | |
| ESD rating, MIL-STD-883D human body model (100 pF, 1500 Ω) | | ESD | 2 | kV | |

| THERMAL RESISTANCE RATINGS | | | | | |
|--|-------------------|---------|---------|------|--|
| PARAMETER | SYMBOL | TYPICAL | MAXIMUM | UNIT | |
| Maximum junction-to-ambient (continuous current) a | R _{thJA} | 290 | 350 | °C/W | |
| Maximum junction-to-foot (Q2) | R _{thJF} | 250 | 300 | C/VV | |

| SPECIFICATIONS (T _J = 25 °C, unless otherwise noted) | | | | | | | | |
|--|---------------------|---|------|-------|-------|------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT | | |
| Off Characteristics | | | | | | | | |
| Reverse leakage current | I _{FL} | V _{IN} = 12 V, V _{ON/OFF} = 0 V | - | - | 1 | μA | | |
| Diode forward voltage | V_{SD} | I _S = -0.8 A | - | -0.84 | -1.2 | V | | |
| On Characteristics | | | | | | | | |
| Input voltage range | V _{IN} | | 1.8 | - | 12 | V | | |
| | R _{DS(on)} | $V_{ON/OFF} = 1.5 \text{ V}, V_{IN} = 4.5 \text{ V}, I_D = 1.1 \text{ A}$ | - | 0.165 | 0.200 | | | |
| On-resistance (p-channel) | | $V_{ON/OFF} = 1.5 \text{ V}, V_{IN} = 2.5 \text{ V}, I_D = 0.9 \text{ A}$ | - | 0.250 | 0.300 | Ω | | |
| | | $V_{ON/OFF} = 1.5 \text{ V}, V_{IN} = 1.8 \text{ V}, I_D = 0.2 \text{ A}$ | - | 0.376 | 0.508 | | | |
| On-state (p-channel) drain-current | I _{D(on)} | $V_{IN-OUT} \le 0.2 \text{ V}, V_{IN} = 5 \text{ V}, V_{ON/OFF} = 1.5 \text{ V}$ | 1 | - | - | Α | | |
| | | $V_{\text{IN-OUT}} \le 0.3 \text{ V}, V_{\text{IN}} = 3 \text{ V}, V_{\text{ON/OFF}} = 1.5 \text{ V}$ | 1 | - | - | ^ | | |

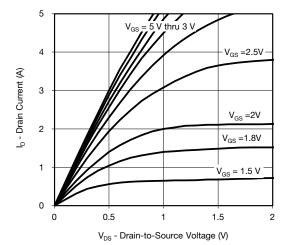
Notes

- a. Surface mounted on FR4 board
- b. V_{IN} = 12 V, $V_{ON/OFF}$ = 8 V, T_A = 25 °C
- c. Pulse test: pulse width $\leq 300~\mu s$, duty cycle $\leq 2~\%$

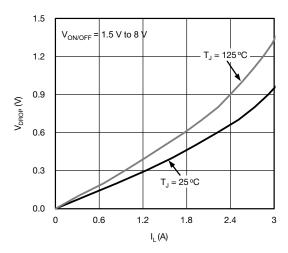
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



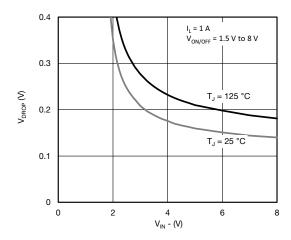
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



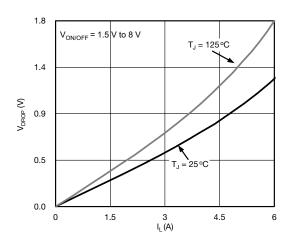
Output Characteristics



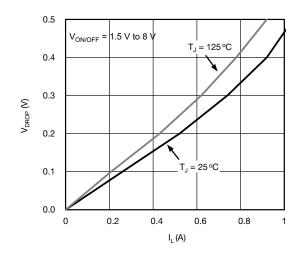
 V_{DROP} vs. I_L at V_{IN} = 2.5 V



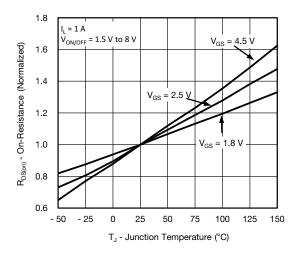
 V_{DROP} vs. V_{IN} at $I_L = 1$ A



 V_{DROP} vs. I_L at V_{IN} = 4.5 V



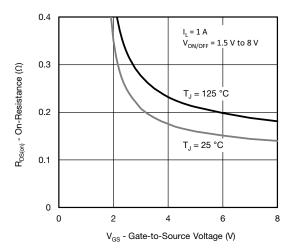
 V_{DROP} vs. I_L at V_{IN} = 1.8 V



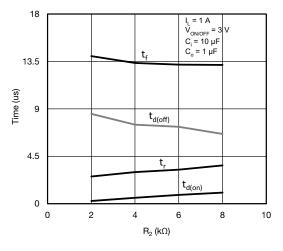
Normalized On-Resistance vs. Junction Temperature



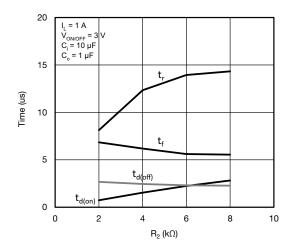
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



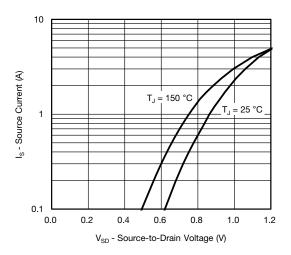
On-Resistance vs. Input Voltage



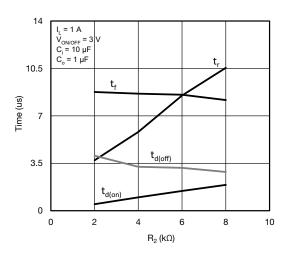
Switching Variation R2 at V_{IN} = 4.5 V, R1 = 20 $k\Omega$



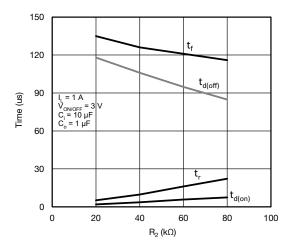
Switching Variation R2 at V_{IN} = 1.8 V, R1 = 20 k Ω



Source-Drain Diode Forward Voltage



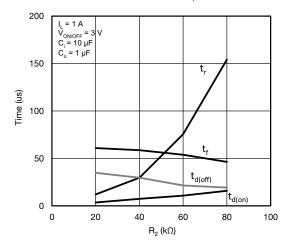
Switching Variation R2 at V $_{\rm IN}$ = 2.5 V, R1 = 20 k Ω

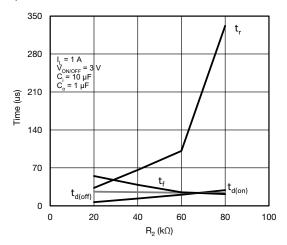


Switching Variation R2 at V_{IN} = 4.5 V, R1 = 300 k Ω



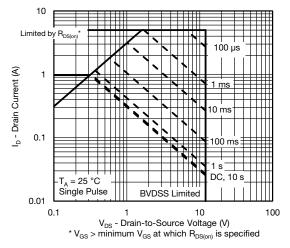
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



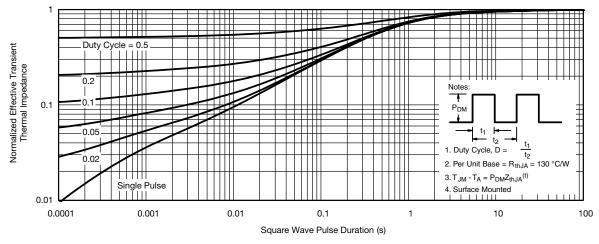


Switching Variation R2 at V_{IN} = 2.5 V, R1 = 300 k Ω

Switching Variation R2 at V_{IN} = 1.8 V, R1 = 300 k Ω



Safe Operating Area, Junction-to-Foot



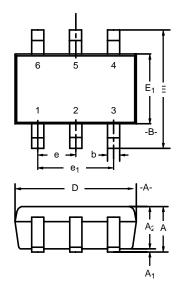
Normalized Thermal Transient Impedance, Junction-to-Ambient

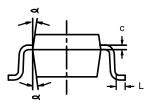
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SC-70: 6-LEADS



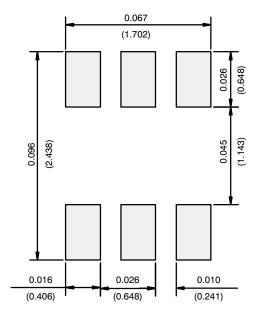


| | MIL | LIMET | ERS | INCHES | | |
|----------------|---------|-------|------|----------|-------|-------|
| Dim | Min | Nom | Max | Min | Nom | Max |
| Α | 0.90 | _ | 1.10 | 0.035 | _ | 0.043 |
| A ₁ | - | _ | 0.10 | - | _ | 0.004 |
| A ₂ | 0.80 | _ | 1.00 | 0.031 | _ | 0.039 |
| b | 0.15 | _ | 0.30 | 0.006 | _ | 0.012 |
| С | 0.10 | - | 0.25 | 0.004 | - | 0.010 |
| D | 1.80 | 2.00 | 2.20 | 0.071 | 0.079 | 0.087 |
| Ε | 1.80 | 2.10 | 2.40 | 0.071 | 0.083 | 0.094 |
| E ₁ | 1.15 | 1.25 | 1.35 | 0.045 | 0.049 | 0.053 |
| е | 0.65BSC | | | 0.026BSC | | |
| e ₁ | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| L | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 |
| کے | 7°Nom | | | | 7°Nom | |

DWG: 5550



RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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